

INTEGRATED CIRCUITS

DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF4502B buffers Strobed hex inverter/buffer

Product specification
File under Integrated Circuits, IC04

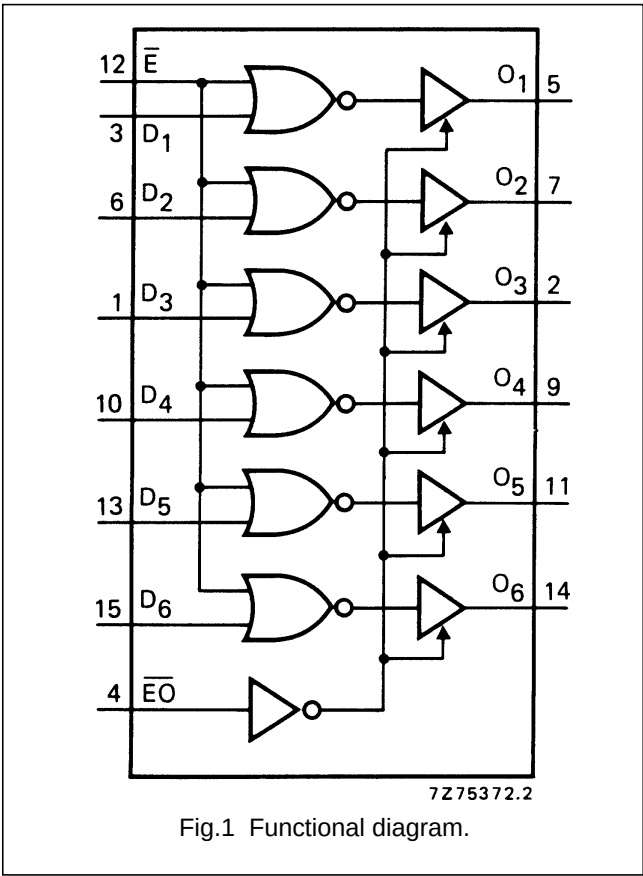
January 1995

Strobed hex inverter/buffer

HEF4502B buffers

DESCRIPTION

The HEF4502B consists of six inverter/buffers with 3-state outputs. When the output enable input ($\overline{EO}$) is HIGH all six outputs (O_1 to O_6) are in the high impedance OFF-state. When the enable input ($\overline{E}$) is HIGH all six outputs are switched to LOW. The outputs have a 2-TTL load drive capability.

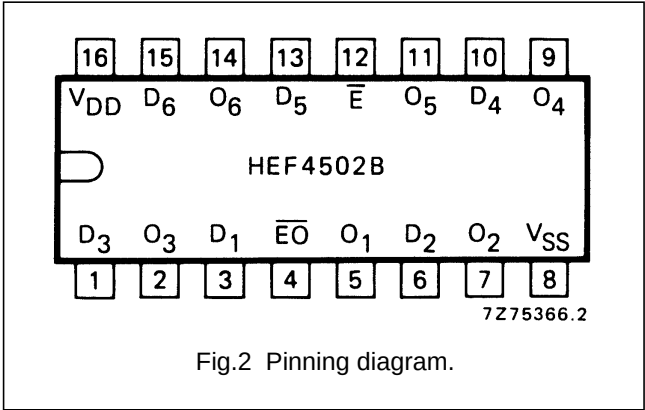


TRUTH TABLE

INPUTS			OUTPUT
D_n	$\overline{E}$	$\overline{EO}$	O_n
L	L	L	H
H	L	L	L
X	H	L	L
X	X	H	Z

Notes

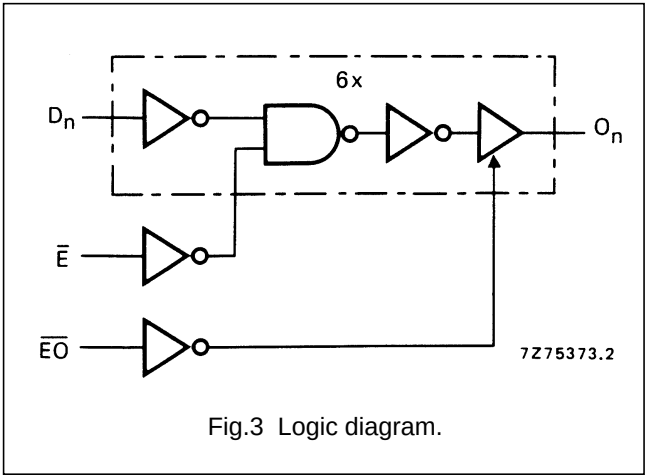
- 1. H = HIGH state (the more pos. voltage)
- L = LOW state (the less pos. voltage)
- X = state is immaterial
- Z = high impedance off state



HEF4502BP(N): 16-lead DIL; plastic (SOT38-1)
HEF4502BD(F): 16-lead DIL; ceramic (cerdip) (SOT74)
HEF4502BT(D): 16-lead SO; plastic (SOT109-1)
(): Package Designator North America

PINNING

D_1 to D_6 data inputs
 $\overline{E}$ enable input
 $\overline{EO}$ output enable input
 O_1 to O_6 3-state outputs



FAMILY DATA, I_{DD} LIMITS category BUFFERS

See Family Specifications

Strobed hex inverter/buffer

HEF4502B
buffers

DC CHARACTERISTICS

 $V_{SS} = 0\text{ V}$

	V_{DD} V	V_{OH} V	V_{OL} V	SYMBOL	$T_{amb} (^{\circ}\text{C})$					
					-40		+ 25		+ 85	
					MIN.	MAX.	MIN.	MAX.	MIN.	MAX.
Output current HIGH	5	4,6		$-I_{OH}$	1,2		1,0		0,8	mA
	10	9,5			3,8		3,2		2,5	mA
	15	13,5			12,0		10,0		8,0	mA
Output current HIGH	5	2,5		$-I_{OH}$	3,8		3,2		2,5	mA
Output current LOW	4,75		0,4	I_{OL}	3,5		2,9		2,3	mA
	10		0,5		12,0		10,0		8,0	mA
	15		1,5		24,0		20,0		16,0	mA

AC CHARACTERISTICS

 $V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; input transition times $\leq 20\text{ ns}$

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power dissipation per package (P)	5	$5\,000 f_i + \sum (f_o C_L) \times V_{DD}^2$	where f_i = input freq. (MHz) f_o = output freq. (MHz) C_L = load capacitance (pF) $\sum (f_o C_L)$ = sum of outputs V_{DD} = supply voltage (V)
	10	$25\,000 f_i + \sum (f_o C_L) \times V_{DD}^2$	
	15	$85\,000 f_i + \sum (f_o C_L) \times V_{DD}^2$	

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AC CHARACTERISTICS

 $V_{SS} = 0$ V; $T_{amb} = 25$ °C; $C_L = 50$ pF; input transition times ≤ 20 ns

	V_{DD} V	SYMBOL	TYP.	MAX.	TYPICAL EXTRAPOLATION FORMULA
Propagation delays $D_n, \bar{E} \rightarrow O_n$ HIGH to LOW	5	t_{PHL}	85	170 ns	77 ns + (0,17 ns/pF) C_L
	10		40	80 ns	37 ns + (0,06 ns/pF) C_L
	15		35	70 ns	33 ns + (0,04 ns/pF) C_L
	5	t_{PLH}	80	160 ns	66 ns + (0,28 ns/pF) C_L
	10		35	70 ns	28 ns + (0,13 ns/pF) C_L
	15		30	60 ns	25 ns + (0,10 ns/pF) C_L
Output transition times HIGH to LOW	5	t_{THL}	25	50 ns	10 ns + (0,30 ns/pF) C_L
	10		12	24 ns	7 ns + (0,11 ns/pF) C_L
	15		8	15 ns	5 ns + (0,07 ns/pF) C_L
	5	t_{TLH}	30	60 ns	5 ns + (0,50 ns/pF) C_L
	10		15	30 ns	3 ns + (0,24 ns/pF) C_L
	15		12	24 ns	3 ns + (0,18 ns/pF) C_L
3-state propagation delays Output disable times $\bar{E}O \rightarrow O_n$ HIGH	5	t_{PHZ}	60	160 ns	
	10		55	140 ns	
	15		55	140 ns	
	5	t_{PLZ}	50	100 ns	
	10		35	70 ns	
	15		30	60 ns	
Output enable times $\bar{E}O \rightarrow O_n$ HIGH	5	t_{PZH}	60	120 ns	
	10		35	70 ns	
	15		30	60 ns	
	5	t_{PZL}	55	110 ns	
	10		25	50 ns	
	15		20	40 ns	